## UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO. : 6,812,530 B2

DATED : November 2, 2004 INVENTOR(S) : Schuegraf et al.

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

## Title page,

Item [56], **References Cited**, FOREIGN PATENT DOCUMENTS, please insert -- JP 401276761-A 11/1989 -- before

"JP 02265248 A 4/1989".

OTHER PUBLICATIONS, please insert -- Wolf et al., "Silicon Processing for the VLSI Era - Volume 1: Process Technology," © 1986 Lattice Press, pages 384-385 (4 pages total) -- after "Lee, B. et al." reference.

## Column 6,

Lines 26 and 62, please delete "suicide" after "comprising" and insert -- silicide --.

Signed and Sealed this

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Fourth Day of October, 2005

JON W. DUDAS
Director of the United States Patent and Trademark Office